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AXIAL LEADED HERMETICALLY SEALED FAST RECTIFIER DIODE

- Low reverse recovery time
- Hermetically sealed in Metoxilite fused metal oxide

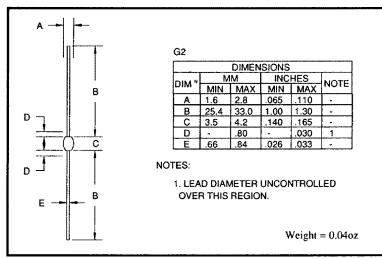
ABSOLUTE MAXIMUM RATINGS (@ 25°C unless otherwise specified)

- Low switching losses
- Low forward voltage drop
- Soft, non-snap off, recovery characteristics

- QUICK REFERENCE DATA
- V_R = 200 1000V
- $I_{\rm F} = 2.00 {\rm A}$
- $t_{rr} = 150 500$ nS
- $I_R = 0.5 \mu A$

	Symbol	1N5615 S2F	1N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Working reverse voltage	Vrwm	200	400	600	800	1000	V
Repetitive reverse voltage	Vrrm	200	400	600	800	1000	V
Average forward current (@ 55°C, lead length 0.375")	I _F (AV)			- 2.0 -		→	А
Repetitive surge current (@ 55°C in free air, lead length 0.375")	I _{FRM}			- 6.0 -		→	A
Non-repetitive surge current (tp = 8.3mS, @VR & Tjmax)	I _{FSM}	-		- 25 -		→	A
Storage temperature range	TSTG			5 to +17	′5 —	→	°C
Operating temperature range	Top	-		5 to +17	'5 		°C

MECHANICAL



These products are qualified to MIL-PRF-19500/429 and are preferred parts as listed in MIL-STD-701. They can be supplied fully released as JAN, JANTX, JANTXV and JANS version. These products are qualified in Europe to DEF STAN 59-61 (PART 80)/029. **SEMTECH**

ELECTRICAL CHARACTERISTICS (@ 25⁰C unless otherwise specified)

	Symbol	1N5615 S2F	1N5617 S4F	1N5619 S6F	1N5621 S8F	1N5623 S0F	Unit
Average forward current max. (pcb mounted; $T_A = 55^{\circ}C$) for sine wave for square wave (d = 0.5)	If(AV) If(AV)	+		- 1.00 - 1.05			A A
Average forward current max. $(T_L = 55^{\circ}C; L = 3/8")$ for sine wave for square wave I^2t for fusing (t = 8.3mS) max.	If(AV) If(AV) I ² t			- 2.00 ·		>	A A A ² S
Forward voltage drop max. @ $I_F = 1.0A$, $T_j = 25^{\circ}C$	VF	4		- 1.2 -			v
Reverse current max. @ V_{RWM} , $T_j = 25^{\circ}C$ @ V_{RWM} , $T_j = 100^{\circ}C$	I _R I _R	←		- 0.5 - - 25 -		+	μΑ μΑ
Reverse recovery time max. 0.5A I _F to 1.0A I _R . Recovers to 0.25A I _{RR} .	t _{rr}	150	150	250	300	500	nS
Junction capacitance typ. @ $V_R = 5V$, f = 1MHz	Cj	27	27	27	18	18	ρF

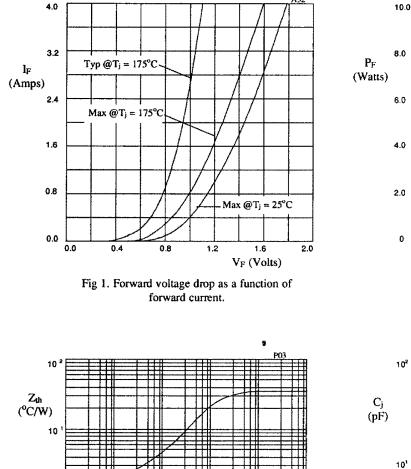
THERMAL CHARACTERISTICS

	Symbol	1N5615 1N5617 1N5619 1N5621 1N5623 S2F S4F S6F S8F S0F	Unit
Thermal resistance - junction to lead Lead length = 0.375" Lead length = 0.0"	R _{əjl} Rəjl		°C/W °C/W
Thermal resistance - junction to amb. on 0.06" thick pcb. 1 oz. copper.	R _{θJA}	← 95	°C/W

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RECTIFIER, up to 1kV, 2A, 150-500ns

A32



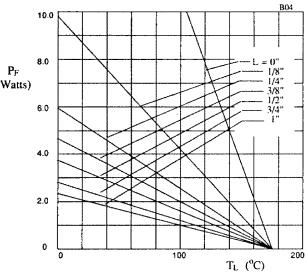


Fig 2. Maximum power versus lead temperature.

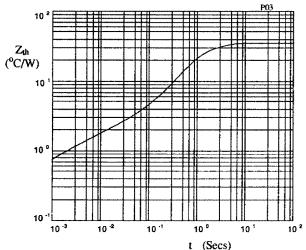


Fig 3. Transient thermal impedance characteristic.

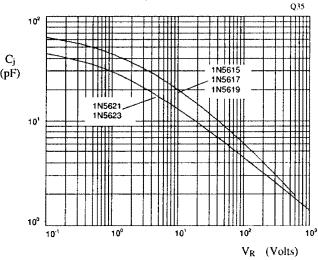


Fig 4. Typical junction capacitance as a function of reverse voltage.



RECTIFIER, up to 1kV, 2A, 150-500ns

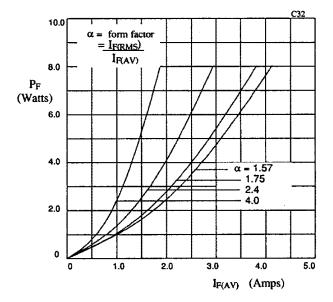


Fig 5. Forward power dissipation as a function of forward current, for sinusoidal operation.

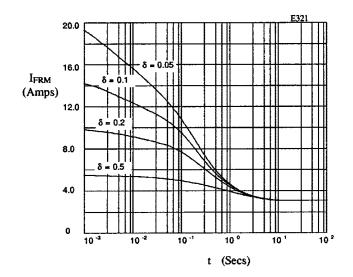


Fig 7. Typical repetitive forward current as a function of pulse width at 55°C; $R_{01L} = 35$ °C/W; V_{RWM} during 1 - δ .

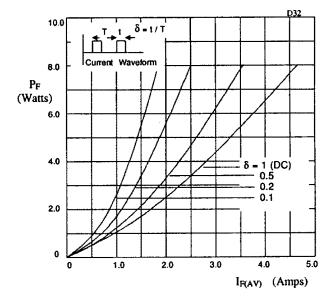


Fig 6. Forward power dissipation as a function of forward current, for square wave operation.

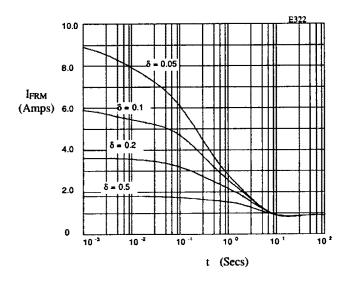


Fig 8. Typical repetitive forward current as a function of pulse width at 100°C; $R_{0JL} = 95$ °C/W; V_{RWM} during 1 - δ .

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